

isc N-Channel MOSFET Transistor

TK12J60U

• FEATURES

- Low drain-source on-resistance:
 R_Ds(on) ≤0.4Ω.
- Enhancement mode:
 Vth =3.0 to 5.0V (VDS = 10 V, ID=1mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Switching Voltage Regulators

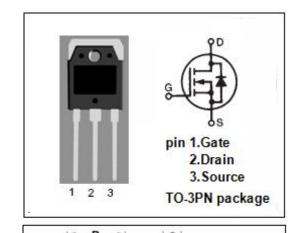


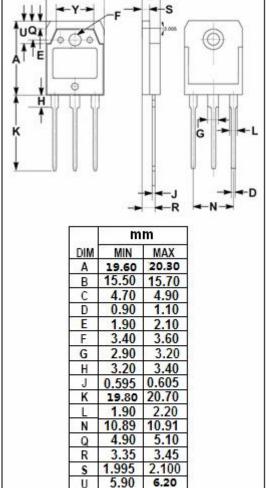
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous	12	Α
I _{DM}	Drain Current-Single Pulsed	24	Α
P _D	Total Dissipation @T _c =25℃	144	W
Tj	Max. Operating Junction Temperature 150		$^{\circ}$
T _{stg}	Storage Temperature -55~150		$^{\circ}$ C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.868	°C/W







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =10mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10V; I _D =1mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =6A			0.4	Ω
lgss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±1	μ А
I _{DSS}	Drain-Source Leakage Current	V _{DS} =600V; V _{GS} = 0V			100	μ А
V _{SDF}	Diode forward voltage	I _{DR} =12A, V _{GS} = 0 V			1.7	V

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